



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

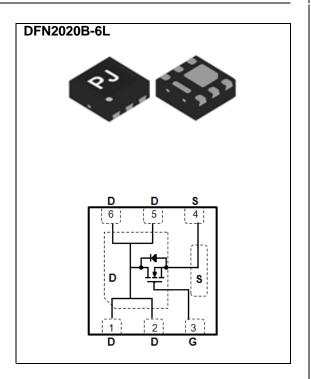
3.2A

Features

- RDS(ON), VGS@10V, ID@3.2A<75mΩ
- RDS(ON), VGS@4.5V, ID@2.0A<90mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: DFN2020B-6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Marking: 460



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	3.2	Α
Pulsed Drain Current		I _{DM}	12.8	А
Power Dissipation	T _a =25°C	_	2.0	W
	Derate above 25°C	P_{D}	16	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient, t<10s (Note 3)		$R_{\theta JA}$	62.5	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.8	2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =3.2A	-	53	75	mΩ		
		V _{GS} =4.5V, I _D =2.0A	-	61	90			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =48V, V _{GS} =0V	-	-	1	uA		
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_g	V _{DS} =48V, I _D =3.0A, V _{GS} =10V (Note 1,2)	-	9.3	-	nC		
Gate-Source Charge	Q_gs		-	2.2	-			
Gate-Drain Charge	Q_{gd}		-	1.9	-			
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	509	-	pF		
Output Capacitance	Coss		-	47	-			
Reverse Transfer Capacitance	Crss		-	23	-			
Turn-On Delay Time	td _(on)	.,	-	3.2	-	ns		
Turn-On Rise Time	tr	V _{DD} =30V, I _D =3.0A,	-	9.7	-			
Turn-Off Delay Time	td _(off)	V_{GS} =10V, R_{G} =3.3 Ω (Note 1,2)	-	18.5	-			
Turn-Off Fall Time	tf		-	6.4	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			-	-	3.2	А		
Diode Forward Current	I _S							
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.75	1.2	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

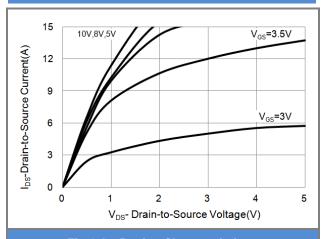


Fig.1 On-Region Characteristics

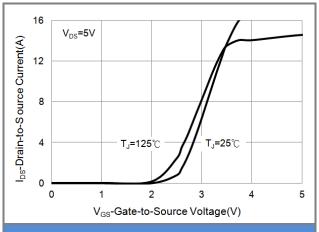


Fig.2 Transfer Characteristics

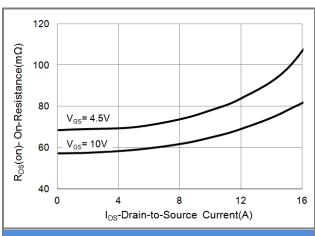


Fig.3 On-Resistance vs. Drain Current

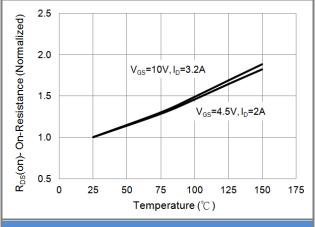
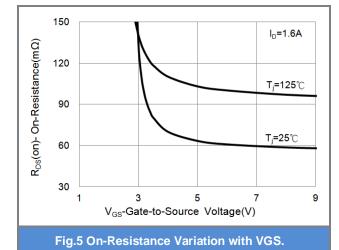


Fig.4 On-Resistance vs. Junction temperature

10



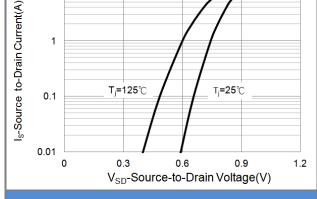


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

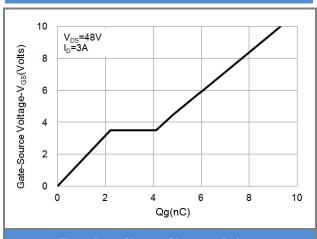
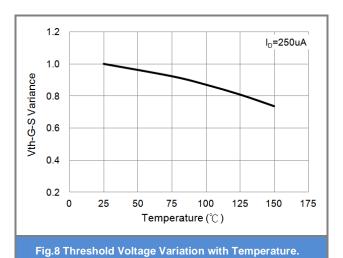


Fig.7 Gate-Charge Characteristics



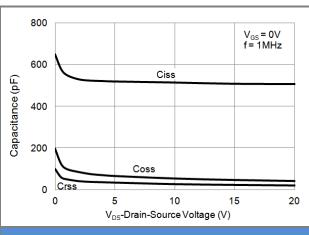


Fig.9 Capacitance vs. Drain-Source Voltage.

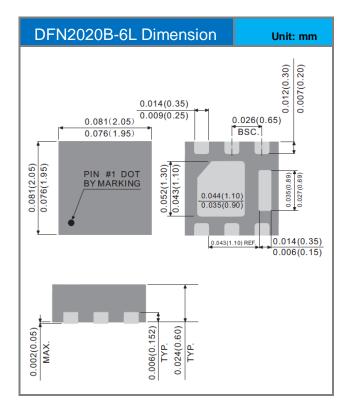


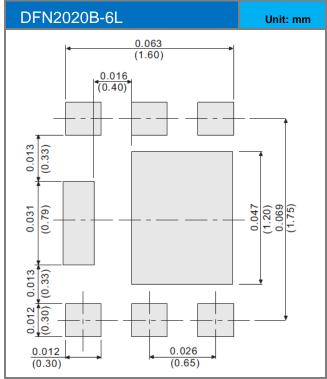


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJQ2460_R1_00001	DFN2020B-6L	3K pcs / 7" reel	460	Halogen free

MOUNTING PAD LAYOUT









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